

ABSTRACT OF THE DISCLOSURE

A surface acoustic wave device is constructed by forming a piezoelectric thin film on a quartz substrate, and in such a manner that the electromechanical coupling coefficient for a Rayleigh wave,  $K^2$ , is enlarged. In this surface acoustic wave device, a piezoelectric thin film is disposed on a quartz substrate, and comb electrodes are disposed on the interface between the quartz substrate and the piezoelectric thin film. The normalized film thickness  $H/\lambda$  of the piezoelectric thin film is preferably at least about 0.05.

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